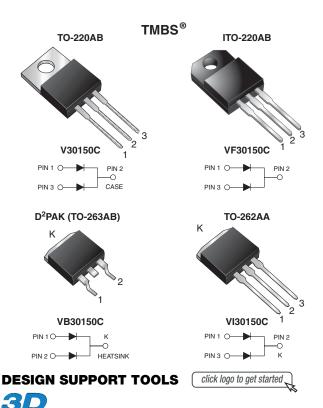


Models Available www.vishay.com

Vishay General Semiconductor

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.56 \text{ V}$  at  $I_F = 5 \text{ A}$ 

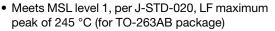


PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 15 A					
V <sub>RRM</sub>	150 V					
I <sub>FSM</sub>	140 A					
V <sub>F</sub> at I <sub>F</sub> = 15 A	0.71 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses





RoHS COMPLIANT

- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB,  $D^2PAK$  (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	V30150C	VF30150C	VB30150C	VI30150C	UNIT	
Max. repetitive peak reverse voltage			150					
per (			30					
Max. average forward rectified current (fig. 1)	per diode	I <sub>F(AV)</sub>	15				A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	140			Α		
Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, L = 60 mH per diode		E <sub>AS</sub>	110		mJ			
Peak repetitive reverse current at $t_p$ = 2 $\mu s$ , 1 kHz, $T_J$ = 38 °C $\pm$ 2 °C per diode		I <sub>RRM</sub>	0.5			Α		
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000		V/µs				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min			1500			V		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150			°C			



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	$I_R = 1.0 \text{ mA}$	T <sub>A</sub> = 25 °C	$V_{BR}$	150 (min.)	-	V		
Instantaneous forward voltage per diode (1)	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub>	0.72	-	V		
	I <sub>F</sub> = 7.5 A			0.81	-			
	I <sub>F</sub> = 15 A			1.11	1.36			
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.56	-			
	I <sub>F</sub> = 7.5 A			0.61	-			
	I <sub>F</sub> = 15 A			0.71	0.79			
Reverse current per diode (2)	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C	I <sub>R</sub>	1.5	-	μΑ		
		T <sub>A</sub> = 125 °C		2	-	mA		
	V <sub>R</sub> = 150 V	T <sub>A</sub> = 25 °C		=	200	μΑ		
		T <sub>A</sub> = 125 °C		4	20	mA		

#### **Notes**

<sup>(2)</sup> Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER SYMBOL V30150C VF30150C VI30150C VI30150C UNI						UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	2.2	4.5	2.2	2.2	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30150C-E3/4W	1.89	4W	50/tube	Tube			
ITO-220AB	VF30150C-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB30150C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB30150C-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI30150C-E3/4W	1.46	4W	50/tube	Tube			

### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

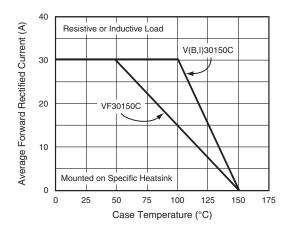


Fig. 1 - Maximum Forward Current Derating Curve

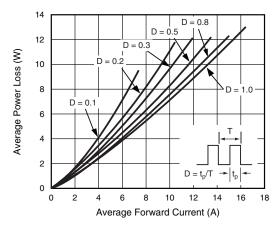


Fig. 2 - Forward Power Loss Characteristics Per Diode

 $<sup>^{(1)}\,</sup>$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle



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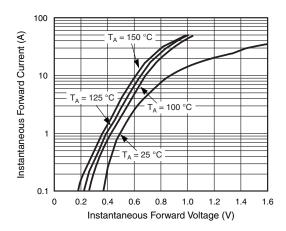


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

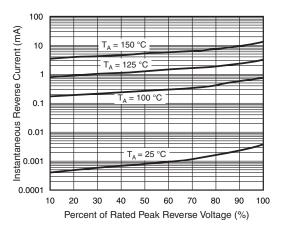


Fig. 4 - Typical Reverse Characteristics Per Diode

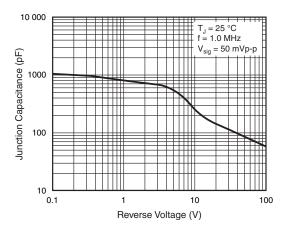


Fig. 5 - Typical Junction Capacitance

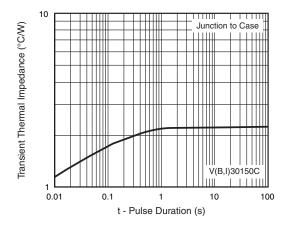


Fig. 6 - Typical Transient Thermal Impedance Per Diode

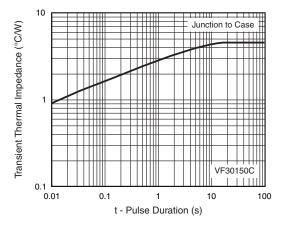
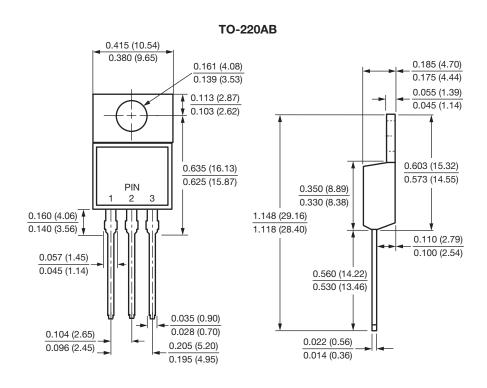


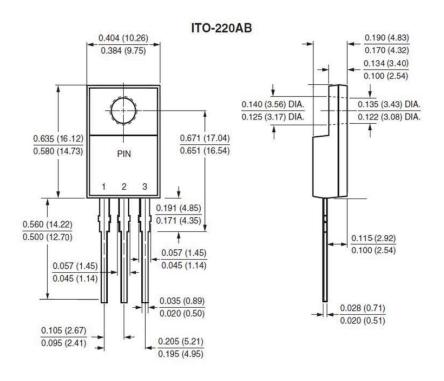
Fig. 7 - Typical Transient Thermal Impedance Per Diode



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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



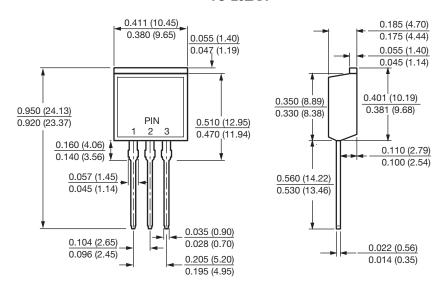




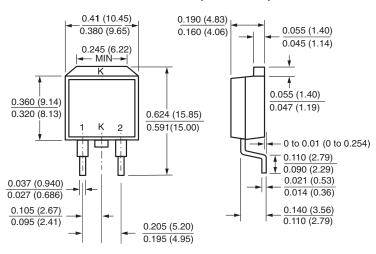


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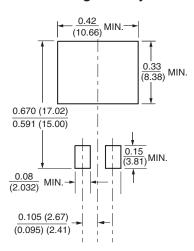
#### **TO-262AA**



### D<sup>2</sup>PAK (TO-263AB)



### **Mounting Pad Layout**





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